## DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

DOCKET NO. TS01-1132

As a below named Inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name;

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled Complementary Metal Oxide Semiconductor Transistor Technology Using Selective Epitaxy Of A Strained Silicon Germanium Layer

| the specification of which (check one)  | BEST AV  | BEST AVAILABLE COPY   |  |
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| X is attached hereto.   |  | WE WELL COPY  |  |
| was filed on  |  |   |  |
| Amuliamena Carial No.   | ·  | i   |  |
| and was amended on  | alisable)  | ·   |  |
| I hereby state that I have reviewed and una<br>amended by any amendment referred to at  | derstand the contents of the ab<br>pove.   | pove Identified specification including the claims, as  |  |
| I acknowledge the duty to disclose inform   | ation which is material to the .56(a).   | examination of this application in accordance with  |  |
| I hereby claim foreign priority benefits un<br>inventor's certificate listed below and hav<br>having a filing date before that of the app | der Title 35. United States Co<br>e also identified below any fo<br>lication on which priority is cl | nde §119 of any foreign application(s) for patent or<br>reign application for patent or inventor's certificate<br>aimed:  |  |
| Prior Foreign Application(s)  |  | Priority Claimed:   |  |
| (Number)  | (Country)  | (Day/Month/Year Filed)  |  |
| (Number)  | (Country)  | (Day/Month/Year Filed)  |  |
| (Application Serial No.)  | (Filing Date) (Status)   | ny United States application(s) listed below and, insofar closed in the prior United States application in the \$\ \text{\text{8112}}. I acknowledge the duty to disclose material (a) which occurred between the filing date of the prior lication:  (patented, pending, abandoned)  are true and that all statements made on information and the with the knowledge that willful false statements and |  |
| the like so made are punishable by fine o<br>and that such willful false statements may   | r imprisonment, or both, under y jeopardize the validity of the                                      | are true and that all statements thate on information and aide with the knowledge that willful false statements and its Section 1001 of Title 18 of the United States Code application or any patent issued thereon.  |  |
| POWER OF ATTORNEY: As a named application and transact all business in the  | inventor, I hereby appoint the le Patent and Trademark Offic   | following attorney(s) and/or agent(s) to prosecute this be connected therewith. (list name & registration no.)  |  |
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